

# STW2040

# High voltage fast-switching NPN power transistor

### **Features**

- High voltage capability
- High DC current gain
- Minimum lot to lot spread for reliable operation

## **Application**

■ Switching mode power supplies

## **Description**

The STW2040 is manufactured using diffused collector in planar technology adopting base island layout.

Josolete Product(s)

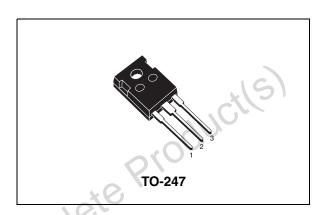


Figure 1. Internal schematic diagram

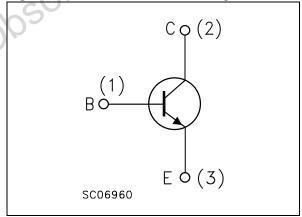


Table 1. Device summary

Order code	Marking	Package	Packaging	
STW2040	W2040	TO-247	Tube	

June 2009 Doc ID 15149 Rev 2 1/10

# 1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>CE</sub> = 0)	700	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	500	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	9	٧
I <sub>C</sub>	Collector current	20	Α
I <sub>CM</sub>	Collector peak current	30	Α
I <sub>B</sub>	Base current	7	Α
I <sub>BM</sub>	Base peak current	10	Α
P <sub>TOT</sub>	Total dissipation at T <sub>c</sub> = 25 °C	125	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

	Symbol	Parameter		Value	Unit
	R <sub>thJC</sub>	Thermal resistance junction-case	max	1	°C/W
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2/10 Doc ID 15149 Rev 2

## 2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C; \text{ unless otherwise specified})$ 

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 700 V			250	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 9 V			10	mA
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA	500			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_C = 6 \text{ A}$ $I_B = 1.2 \text{ A}$		0.2	0.5	V
		$I_C = 12 \text{ A}$ $I_B = 2.4 \text{ A}$		0.3		V
		$I_C = 20 \text{ A}$ $I_B = 4 \text{ A}$		0.6		V
v (1)	Base-emitter saturation	$I_C = 6 \text{ A}$ $I_B = 1.2 \text{ A}$			1.2	V
V <sub>BE(sat)</sub> <sup>(1)</sup>	voltage	$I_C = 12 \text{ A}$ $I_B = 2.4 \text{ A}$			1.5	V
		$I_C = 10 \text{ mA}$ $V_{CE} = 5 \text{ V}$	8			
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = 6 A$ $V_{CE} = 5 V$	15	21	27	
		$I_C = 12 \text{ A}$ $V_{CE} = 5 \text{ V}$	10			
	Resistive load	V <sub>CC</sub> = 200 V				
t <sub>on</sub>	Turn-on time	$V_{BE(off)} = -5 \text{ V } I_{C} = 7.5 \text{ A}$		140		ns
t <sub>f</sub>	Fall time	$I_{B(on)} = 1.5 A$		100		ns
t <sub>s</sub>	Storage time	$I_{B(off)} = -3 A$		1.6		μs
- +	Inductive load	V <sub>CL</sub> = 250 V				
101	Storage time	$V_{BE(off)} = -5 \text{ V } I_{C} = 7.5 \text{ A}$		1.8		μs
t,	Fall time	$I_{B(on)} = 1.5 A$		30		ns
KO4	i an ano	$I_{B(off)} = -3 A$				113

<sup>1.</sup> Pulsed duration = 300 μs, duty cycle ≤ 1.5 %

STW2040 **Electrical characteristics** 

#### 2.1 **Electrical characteristic (curves)**

Figure 2. Safe operating area

Ic(A) I<sub>C</sub> MAX PULSED PULSE OPERATION \* 10 Ic MAX CONT 0.1 For single non repetitive pulse 0.01  $V_{CE}(V)$ 

Figure 3. **Derating curve** 

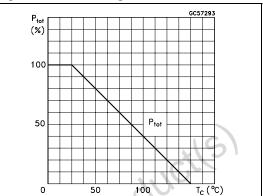
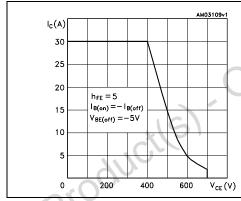


Figure 4. Reverse biased safe operating area

Figure 5. **Output characteristics** 



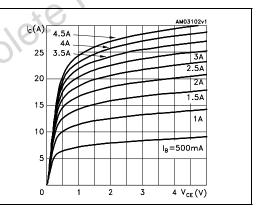
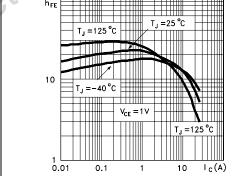
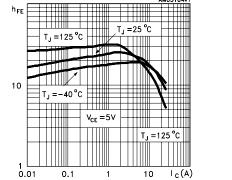


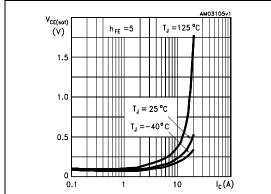
Figure 6. DC current gain (V<sub>CE</sub> = 1 V) Figure 7. DC current gain  $(V_{CE} = 5 V)$  $T_J = 25$  °C  $T_J = 25 \,^{\circ}C$ 





57 4/10 Doc ID 15149 Rev 2

Figure 8. Collector-emitter saturation Figure 9. Base-emitter saturation voltage voltage



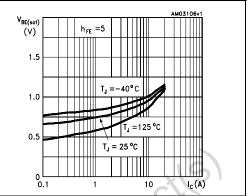
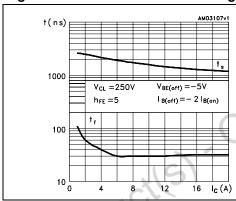
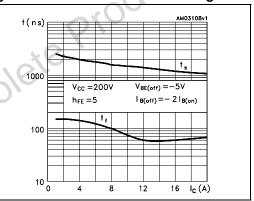


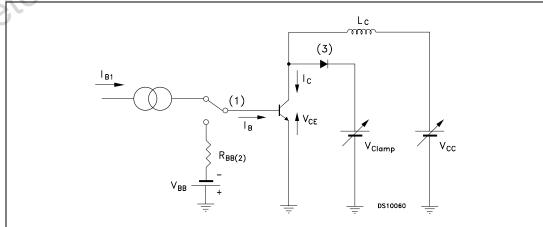
Figure 10. Inductive load switching time Figure 11. Resistive load switching time





# 2.2 Test circuits

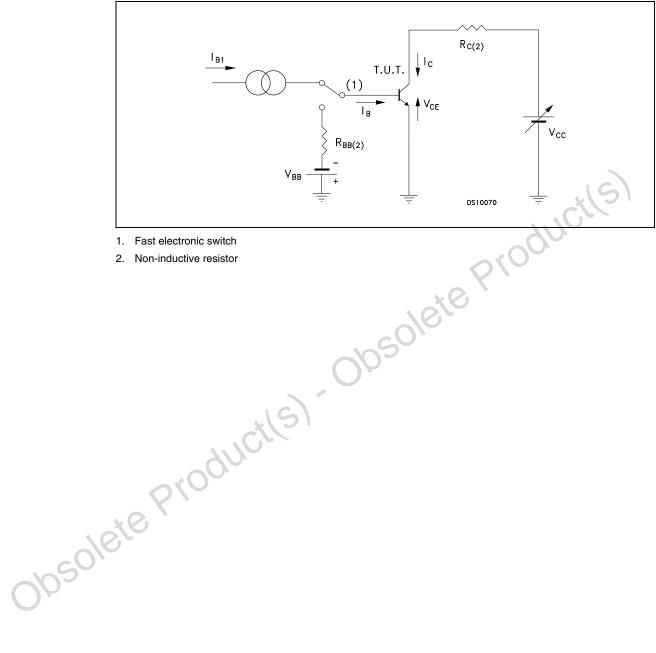
Figure 12. Inductive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier

**Electrical characteristics** STW2040

Figure 13. Resistive load switching test circuit



57

## 3 Package mechanical data

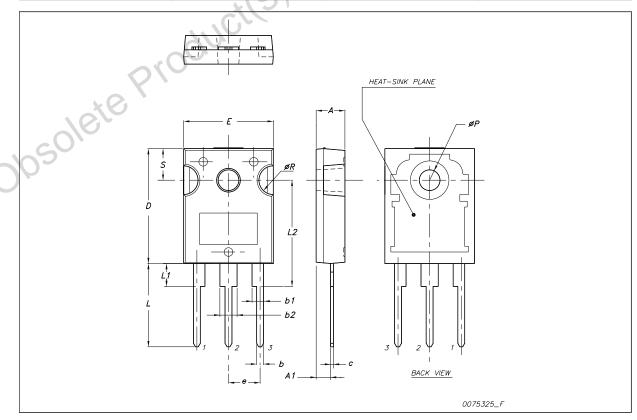
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577

Obsolete Product(s). Obsolete Product(s)

### TO-247 mechanical data

Dim.	mm.			
	Min.	Тур.	Max.	
A	4.85		5.15	
A1	2.20		2.60	
b	1.0		1.40	
b1	2.0		2.40	
b2	3.0		3.40	
С	0.40		0.80	
D	19.85		20.15	
E	15.45		15.75	
е		5.45		
L	14.20	40,	14.80	
L1	3.70	16/	4.30	
L2		18.50		
øP	3.55	103	3.65	
øR	4.50		5.50	
S	16	5.50		



STW2040 Revision history

# 4 Revision history

Table 5. Document revision history

	Date	Revision	Changes
	07-Nov-2008	1	Initial release.
	10-Jun-2009	2	Document status promoted from preliminary data to datasheet.
Obsole	ie Prod	,uct!	Document status promoted from preliminary data to datasheet.

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